New Product

SS2P2L & SS2P3L

Vishay General Semiconductor

## Low V<sub>F</sub> High Current Density Surface Mount Schottky Barrier Rectifiers

### eSMP<sup>™</sup> Series



DO-220AA (SMP)

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 A				
V <sub>RRM</sub>	20 V, 30 V				
I <sub>FSM</sub>	50 A				
E <sub>AS</sub>	11.25 mJ				
V <sub>F</sub>	0.45 V				
T <sub>J</sub> max.	150 °C				

## FEATURES

- · Very low profile typical height of 1.0 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
  - Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

## TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheelling, dc-to-dc converters, and polarity protection applications.

## **MECHANICAL DATA**

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS2P2L	SS2P3L	UNIT	
Device marking code		22L	23L		
Maximum repetive peak reverse voltage	V <sub>RRM</sub> 20 30			V	
Maximum average forward rectified current (Fig. 1)	I <sub>F(AV)</sub>	2.0		A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	50		A	
Non-repetitive avalanche energy at $I_{AS}$ = 1.5 A, L = 10 mH, $T_{J}$ = 25 $^{\circ}\text{C}$	E <sub>AS</sub>	11.25		mJ	
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000		V/us	
Operating junction and storage temperature range	T <sub>J,</sub> T <sub>STG</sub>	- 55 to + 150		°C	

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	I <sub>F</sub> = 2 A I <sub>F</sub> = 2 A	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	V <sub>F</sub>	0.45 0.38	0.50 0.45	V
Maximum reverse current at rated $V_R^{(2)}$		T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	- 9.0	200 20	μA mA
Typical junction capacitance	4.0 V, 1 MHz		CJ	130		pF

#### Notes:

(1) Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle (2) Pulse test: Pulse width  $\leq$  40 ms

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 For technical questions within your region, please contact one of the following:

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<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	SS2P2L	SS2P3L	UNIT
Typical thermal resistance <sup>(1)</sup>	${f R}_{ heta JA} \ {f R}_{ heta JL} \ {f R}_{ heta JC}$	115 15 20		°C/W

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas.  $R_{\theta JL}$  is measured at the terminal of cathode band.  $R_{\theta JC}$  is measured at the top centre of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS2P3L-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
SS2P3L-E3/85A	0.024	85A	10 000	13" diameter plastic tape and reel		
SS2P3LHE3/84A <sup>(1)</sup>	0.024	84A	3000	7" diameter plastic tape and reel		
SS2P3LHE3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified

## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

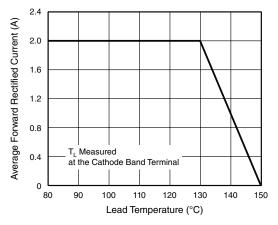


Figure 1. Forward Current Derating Curve

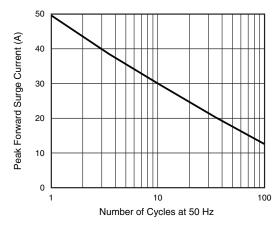


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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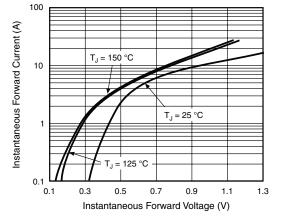


Figure 3. Typical Instantaneous Forward Characteristics

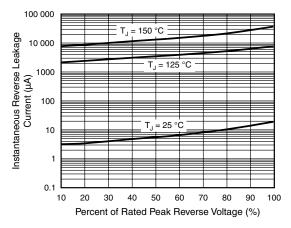


Figure 4. Typical Reverse Leakage Characteristics

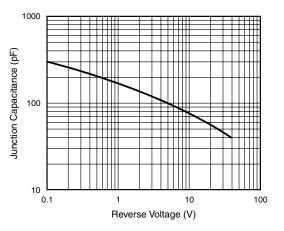


Figure 5. Typical Junction Capacitance

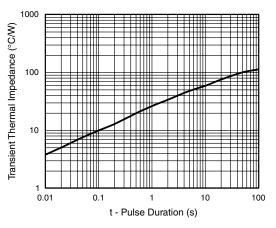
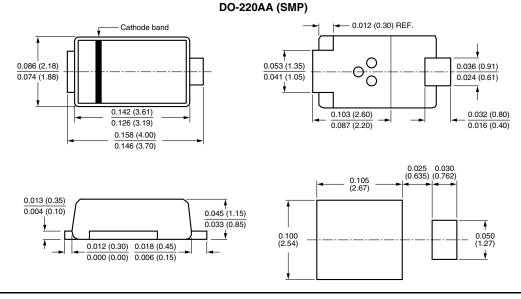


Figure 6. Typical Transient Thermal impedance

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



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